A micromachined artificial sensor comprises a support coupled to and movable with respect to a substrate. A polymer, high-aspect ratio cilium-like structure is disposed on and extends out-of-plane from the support. A strain detector is disposed with respect to the support to detect movement of the support.


* cited by examiner
FIG. 6

Resistance % Change

Tip Deflection (µm)

On-Axis

Off-Axis

0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6

0 2 4 6 8 10 12
MICROMACHINED ARTIFICIAL HAIRCELL

PRIORITY CLAIM

This application claims the benefit of U.S. Provisional Application Ser. No. 60/810,800, filed Jun. 2, 2006, under 35 U.S.C. §119.

STATEMENT OF GOVERNMENT INTEREST

This invention was made with Government assistance under USAF/AFOSR Contract No. F49620-02-2-0496, NASA Contract No. NAG5-8781 and NSF Contract No. IIS0080639, IIS99-84954. The Government has certain rights in this invention.

FIELD OF THE INVENTION

This invention relates generally to the field of microscale devices. The invention also relates generally to the field of artificial sensors.

BACKGROUND OF THE INVENTION

Humans and other animals are able to perceive and process environmental conditions using various sensory attributes. For example, animal skin and hair provide tactile and flow sensing for perception in land and/or water environments. Synthetic (engineered) sensors, on the other hand, typically are constructed on many different physical principles, such as heat and resistance, in an attempt to obtain similar information. Animal sensory systems have attributes that are more elegant and efficient than known engineered sensors. Engineered sensors, such as micromachined sensors, have been previously developed based on a number of sensing methods. Microfabrication offers benefits including high spatial resolution, fast time response, integrated signal processing, and potentially low costs. Examples of microfabricated sensors include thermal (hot-wire) anemometers and artificial haircells.

In numerous species, including humans, the biological haircell sensor serves as the building block for sensing systems with amazing capabilities. A typical haircell in animals provides a biological mechanoreceptor. FIG. 1 shows a demonstration of a spider receptor haircell sensor. The haircell includes a cilium attached to tissue via a cuticular membrane. The cilium is connected to a neuron. Bending the cilium, as shown in the right side of FIG. 1, affects a signal path, producing a changed signal. This change is used for reception.

The functions of animal haircells have been very closely studied by biologists over the years. However, in recent years, with the development of micromachining techniques, researchers have started to mimic the stimulus-transmission mechanism of biological sensing systems.

Artificial haircells have been produced by the present inventors and by others. One example artificial haircell provided by one or more of the present inventors is described in J. Chen et al., a cilium is anchored by one or more rigid metal supports. The cilium prebendsly is made of a surface micromachined polymer and includes a stiff permutaloy plating. A strain gauge is attached at the base of the cilium and includes a resistor, such as a nichrome resistor, on a polyimide backing. When an external force is applied to the cilium, the cilium deflects, causing the strain gauge to stretch or compress. The resulting change in resistance is detected.

Yet another artificial haircell provided by the one or more of the present inventors, as disclosed in J. Engel, J. Chen, D. Bullen, and C. Liu, “Polyurethane Rubber as a MEMS Material: Characterization and Demonstration of an All-Polymer Two-Axis Artificial Haircell Flow Sensor,” 18th IEEE International Conference on Micro Electro Mechanical Systems, MEMS 2005, Miami Beach, Fla. USA, January 2005, includes a sensor made entirely of polymer materials from a substrate level up. Polyurethane elastomers are utilized for sensing and structures. Such a haircell can detect two-axis deflection of a vertical polyurethane cilium using, for example, a plurality of carbon-impregnated polyurethane force sensitive resistors disposed at a base of the cilium.

SUMMARY OF THE INVENTION

According to example embodiments of the present invention, a micromachined artificial sensor comprises a support coupled to and movable with respect to a substrate. A polymer, high-aspect ratio cilium-like structure is disposed on and extends out-of-plane from the support. A strain detector is disposed with respect to the support to detect movement of the support.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a schematic view of a typical spider receptor haircell sensor;

FIG. 2 is a perspective view and cross-sectional view of an artificial haircell according to an embodiment of the present invention;

FIG. 3 is a scanning electron microscope (SEM) view of a released artificial haircell according to an embodiment of the present invention;

FIGS. 4A-4G show steps in an example fabrication process for an artificial haircell, according to an embodiment of the present invention;

FIGS. 5A-5B are SEM views of SU-8 hairs obtained with optical filtering (showing a “T-topping effect”) and without optical filtering, respectively;

FIG. 6 shows results of a tip deflection test for an example artificial haircell, indicating resistance change due to on-axis and off-axis deflection;

FIGS. 7A-7B show sensor output voltage vs. flow angle and standard deviation of sensor output vs. flow angle for an example artificial haircell;

FIG. 8 compares sensor output to stage velocity for a series of velocity sweep runs;

FIG. 9 shows an atomic force microscope (AFM) output of a resonant frequency test, where the AFM operates in non-contact mode.
FIG. 10 compares dipole position to amplitude for an example dipole experiment; and FIG. 11 is an SEM view of a pair of artificial haircells oriented orthogonally.

DETAILED DESCRIPTION

Sensing capacities have been captured through micromachined artificial haircells. However, it is desirable to improve robustness, flexibility, and/or sensitivity for artificial sensors in various real-world sensing environments.

Embodiments of the present invention provide artificial sensors that can mimic one or more animal sensors. Such artificial sensors can be designed or modified for use in any of various sensor functions. Preferably, such artificial sensors exhibit a desired degree of robustness, flexibility, and sensitivity. Particular artificial sensors according to embodiments of the present invention can be designed and produced at relatively low cost, and on a large scale if needed, while allowing the flexibility and adaptability to substitute for various types of sensors found in nature.

Generally, a micromachined artificial haircell according to an example embodiment of the present invention includes a high-aspect ratio (e.g., greater than 1:1) and tall (e.g., at or above 20 microns) cilia-like structure, i.e., a cilia-like artificial hair, attached to a movable support. The hair is positioned generally out-of-plane of the support so that it can receive a force from any of a variety of sources and displace in response to the force. Preferably, the hair is made from a polymer material. Displacement of the hair couples the force to the movable support, and in turn causes movement in the support. A strain detector is provided on the support to sense displacement of the support. Preferably, the strain detector includes one or more piezoresistors formed by doping all of part of the support.

The support may be, as nonlimiting examples, a cantilevered support, a beam, a membrane, and/or a paddle on which the hair is disposed. The support may be formed, as a nonlimiting example, from silicon by micromachining. The configuration, flexibility, etc. of the support can vary depending on the range of inputs expected (i.e., the operational envelope). An example support includes a silicon paddle, which preferably but not necessarily is a cantilever or beam. In an example embodiment, the paddle is a single support (fixed-free) cantilever beam. Under this configuration, the force coupled through the hair to the beam is introduced as a displacement of the hair, in turn causing the support that is coupled to the hair (e.g., formed in or on the hair) to transduce pressure into deformation of the support and provide an electrical change (such as piezoresistivity or piezoelectricity) which can be used to measure strain in the support.

An exemplary strain detector includes one or more strain gauges, such as piezoresistive or piezoelectric sensors, which provide one or more signals used to measure strain based on displacement of the hair. The strain gauge, such as a piezoresistive or piezoelectric sensor or sensors, preferably is incorporated into the support (e.g., membrane, beam, or cantilever). This may be done, for example, by doping the support or part of the support. Alternatively, a piezoelectric or piezoresistive sensor or sensors can be deposited on the structure (such as by metal, screen printing, etc.). The purpose of the strain detector is to convert strain in the support structure into an electrical change via resistance change and/or voltage output (e.g., due to a bridge configuration). In an example embodiment, the support is made from a silicon-on-insulator (SOI) wafer to create high sensitivity piezoresistance. For example, the hair may be disposed on a paddle supported by beams, so that the paddle and beams provide the support, and the strain detector may be a piezoresistive sensor disposed on the beams or formed within the beams.

In an example operation, a force due to an input causes displacement of the hair, in turn causing the support that is supporting the hair to be strained. This strain is detected by the strain detector. The input may vary depending on the configuration or environment of the hair, as described above.

Turning now to the drawings, FIGS. 2-3 show a cilia-based artificial haircell 20 according to an example embodiment of the invention. Generally, the example haircell 20 is a cilia-based silicon piezoresistive sensing device. The haircell 20 includes a cilia-like hair 22 disposed on a silicon paddle 24 supported by a set of silicon beams 26. Together, the paddle 24 and the beams 26 provide a support for the hair 22. The paddle 24 and beam structure 26 is cantilevered from a preferably silicon substrate 28, which may be, for example, a chip or portion of a chip. Nonlimiting example cantilever dimensions (e.g., the dimensions of the beam structure 26) include a length of 100 µm (e.g., from the attachment point of the bulk silicon substrate 28 to the beginning of the paddle 24), a width of 20 µm (e.g., the sum of the widths of the two beams shown, without the interposed gap), and a thickness of 2 µm. A cavity 29 is provided in the substrate 28 and below the paddle 24 to permit movement of the paddle and the beams 26 in response to displacement of the hair 22.
The substrate 28 may include one or more electrical connections and components, such as but not limited to a series of on-chip resistors 30 forming a Wheatstone bridge. The beams 26 are doped to form strain detectors in the form of strain gauges 32 at a base, and these strain gauges are electrically connected to the resistors 30. The strain gauges may be provided by doping a connection point or connection area between the beams 26 and the substrate 28, or the entire support may be doped. Wiring for connecting the strain gauges 32 to the resistors 30 may be, as non-limiting examples, gold, gold-titanium, aluminum, etc. For certain contacts, annealing may be performed to provide the contact. Annealing methods will be understood by those of ordinary skill in the art.

The example hair 22 is made of a high aspect ratio SU-8 structure with 80 µm diameter and 500-750 µm height. Another exemplary, non-limiting height range for the hair 22 is 600-800 µm. An exemplary formation process for the hair 22 includes a single spin of SU-8 2075 and photolithography using a Karl Suss aligner.

An example process flow for fabricating the haircell 20 is shown in FIGS. 4A-4G. This example process is robust and takes advantage of high etching selectivity associated with the deep reactive ion etching (DRIE) process. In the example fabrication process, a substrate, such as a silicon-on-insulator (SOI) wafer 40, is subjected to (e.g., doped by) ion implantation (FIG. 4A) to define piezoresistors 42 forming the strain gauges 32 and the Wheatstone bridge resistors 30. In this example fabrication process, all of the resistors 30 for the Wheatstone bridge are fabricated on-chip to minimize the thermal effect of a flow sensor.

Next, as shown in FIG. 4B, an oxide insulator 44 is deposited on the substrate 40 and patterned to provide contact windows 46 to the piezoresistors 42. Metal contact pads 48 are deposited and patterned to define the electrical connections (FIG. 4C). For example, a gold lift-off may be used, though other wiring, such as aluminum wiring, is also contemplated. To define the beams and paddles, a front-side Si etch 50 is performed (FIG. 4D). A DRIE backside etch follows (FIG. 4E), forming backside cavities 52 all the way to an oxide 54.

The cilia-like hair 22 is then formed, for example, defined using a SU-8 process (FIG. 4F). The SU-8 process reduces manual handling of the devices and allows batch fabrication of haircell devices. Preferably, a high-pass optical filter is used during exposure to minimize or eliminate the “T-topping” effect of the SU-8 structures. Examples of SU-8 structures with and without the “T-topping” effect, respectively, are shown in FIGS. 5A-5B. Finally, a BHF etch removes the oxide barrier 54 and releases the beam structure (FIG. 4G).

For device characterization of the example haircell 20, a tip-deflection test, resonant frequency test, sensitivity threshold test, and preliminary dipole experiments were performed. The example haircell 22 allows low-frequency (<1 kHz) underwater flow sensing with the capability of detecting very low flow velocity.

For example, as shown in FIG. 6, the tip-deflection test shows very directional response with 0.1% resistance change due to on-axis deflection (e.g., down the length of the beam) and almost no response due to off-axis deflection (e.g., across the length of the beam). Based on the deflection test, the gauge factor of the silicon strain gauge is determined to be 40. FIGS. 7A-7B show another set of tests run for sensor directionality performance. FIG. 7A shows sensor output voltage vs. flow angle, and FIG. 7B shows a standard deviation of sensor output vs. flow angle. An angular resolution of 2.16° with a standard deviation of 0.0151 was determined.

The velocity detection threshold is tested by the underwater dipole experiment. Example results are shown in FIG. 8. By sweeping the dipole vibration frequency and translating it into flow velocity, it was observed that the example haircell sensor can detect flow velocity down to 2 mm/s. This low-velocity detection capability is very significant in real-world testing.

The resonant frequency of different geometries has been tested using atomic force microscopy (AFM) under non-contact mode. The resonant frequencies are on the order of a couple of KHz, which satisfies a design specification of low frequency detection. FIG. 9 shows an AFM output of an example resonant frequency test. Preliminary dipole experiments were also performed, and a result showing a peak of response at the position of the example haircell sensor is shown in FIG. 10.

Arrays of haircells 20 may be formed on one or more substrates 28. Multiple haircell sensors may be oriented, for example, orthogonally, to detect flow deflection with precision as high as 1 degree. For example, the longitudinal axis of the supports for the respective haircells may be disposed orthogonally to one another to provide sensitivity along the respective axes. An example of arrayed haircell sensors is shown in FIG. 11. One or more arrays of sensors may be provided for hydrodynamic flow imaging and object tracking for military use and study of nature. Various materials and packing methods may be used to improve the robustness of the haircell device.

Within haircell sensor arrays, the individual haircells may be configured as desired to sense different inputs, and even vary among the haircells on a single substrate 28. For example, the length of the hair can change, and frequency response, orientation, dynamic range, etc. can be varied as needed. Thus, due to the design of the hair (mechanical features) and/or the accessory coupling mechanism (e.g., coating, etc.), various types of sensing can occur, even on a single substrate if desired.

Haircells according to example embodiments provide a simple receptor that may serve as a modular building block for a variety of sensors, thus providing multi-modal sensing, including applications beyond flow sensing and simple mechanical sensing, if desired. Such various types of sensors may be provided, for example, by varying one or more features of the preferred haircell. For example, haircells according to example embodiments may be used as an acoustic sensor, vibration sensor (1-3 axes), equilibrium sensor, magnetic sensor, airflow sensor (1-3 axes), waterflow sensor (1-3 axes), tactile sensor, accelerometer (e.g., via direct vibration), chemical, biological, or biochemical sensor, and other types of sensors. Cilia operating, for example, as ear hairs may be used to provide a microphone-like device.

While various embodiments of the present invention have been shown and described, it should be understood that other modifications, substitutions, and alternatives are apparent to one of ordinary skill in the art. Such modifications, substitutions, and alternatives can be made without departing from the spirit and scope of the invention, which should be determined from the appended claims. Various features of the invention are set forth in the appended claims.

What is claimed is:

1. A micromachined artificial sensor comprising:
   a support coupled to and movable with respect to a substrate;
a polymer, high-aspect ratio cilia-like structure disposed on and extending out-of-plane from said support;
a strain detector disposed with respect to said support to detect movement of said support;
wherein said support comprises silicon; and
wherein said support is formed by micromachining the substrate to provide a cavity disposed under said support.

2. The artificial sensor of claim 1, wherein said support comprises at least one cantilevered beam.

3. A micromachined artificial sensor comprising:
a support coupled to and movable with respect to a substrate;
a polymer, high-aspect ratio cilia-like structure disposed on and extending out-of-plane from said support;
a strain detector disposed with respect to said support to detect movement of said support;
wherein said support comprises a paddle supported by at least two cantilevered beams, and wherein said cilia-like structure is disposed on said paddle.

4. The artificial sensor of claim 1, wherein said strain detector comprises a piezoresistive strain gauge formed by doping a portion of said support.

5. The artificial sensor of claim 4, wherein the strain gauge is disposed at or near a connection between said support and the substrate.

6. The artificial sensor of claim 1, wherein said cilia-like structure comprises a generally cylindrical structure having an aspect ratio of greater than 1:1 height:diameter.

7. The artificial sensor of claim 1, wherein said cilia-like structure comprises an epoxy.

8. The artificial sensor of claim 1, wherein said cilia-like structure comprises SU-8 epoxy spun onto said support.

9. The artificial sensor of claim 1, further comprising:
a transducer disposed on said cilia-like structure that deforms or moves in response to a stimulus to move said cilia-like structure.

10. The artificial sensor of claim 9, wherein said transducer comprises at least one of a magnetic transducer, a vibration transducer, an acoustic transducer, a chemical transducer, a biological transducer, and a biochemical transducer.

11. A micromachined sensing apparatus comprising:
a silicon substrate;
a silicon support coupled to and movable with respect to said substrate, wherein a cavity is defined beneath said support;
a polymer, high-aspect ratio cilia-like structure disposed on and extending out-of-plane from said support;
a strain detector disposed with respect to said support to detect movement of said support.

12. The sensing apparatus of claim 11, wherein said support is formed by micromachining said silicon substrate, and wherein said strain detector is formed by doping a portion of said silicon support to provide a piezoresistive strain gauge.

13. The sensing apparatus of claim 11, wherein said cilia-like structure comprises a generally cylindrical structure having an aspect ratio of greater than 1:1 height:diameter.

14. The sensing apparatus of claim 11, further comprising:
a transducer disposed on said cilia-like structure that deforms or moves in response to a stimulus to move said cilia-like structure.

15. A micromachined sensing apparatus comprising:
a silicon substrate;
a silicon support coupled to and movable with respect to said substrate, wherein a cavity is defined beneath said support;
a polymer, high-aspect ratio cilia-like structure disposed on and extending out-of-plane from said support;
a strain detector disposed with respect to said support to detect movement of said support;
further comprising:
an additional silicon support coupled to and movable with respect to said substrate, wherein a cavity is defined beneath said additional support;
an additional polymer, high-aspect ratio cilia-like structure disposed on and extending out-of-plane from said additional support;
an additional strain detector disposed with respect to said additional support to detect movement of said additional support;
wherein said additional silicon support is disposed on said substrate at an angle with respect to said silicon support.

16. The sensing apparatus of claim 15, wherein said additional silicon support, said additional cilia-like structure, and said additional strain detector are disposed to have an optimal flow sensitivity at a different angle than an optimal flow sensitivity of said silicon support, said cilia-like structure, and said strain detector.

17. The sensing apparatus of claim 15, wherein said additional silicon support has a longitudinal axis that is generally orthogonal to a longitudinal axis of said silicon support.